

APPLICATION NO. 09/662004	CONT/PRIOR F	CLASS 438	SUBCLASS 192	ART-UNIT 2812 2823	EXAMINER R. K. H. S. J. J. J.
APPLICANTS Kazuhiro Itonaga Atsuo Yamamoto Haruo Nakano Isao Miyahara					
TITLE Method of forming insulating film and method of fabricating semiconductor device					
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